NSN 5961-01-178-0962

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-178-0962 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Overall Diameter:** 0.364 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-5 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 5.0 breakdown voltage, collector-to-emitter, base open all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Capacitance Rating In Picofarads:** 2.0 all semiconductor device diode **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0